

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-25	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V_{EBO}	-7.5	V
Base Current	I _B	-500	mA
Continuous Collector Current	Ic	-3.5	Α
Peak Pulse Collector Current	I _{CM}	-10	Α

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	` ,		W	
Linear Derating Factor	(Note 6)	- P _D	1.7 13.6	mW/°C	
Thermal Desistance, Junction to Ambient	(Note 5)	D	113		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	73	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	18.61		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

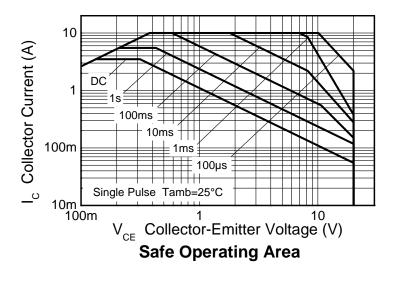
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

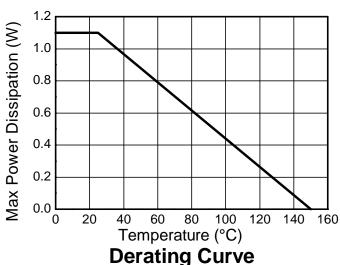
Notes:

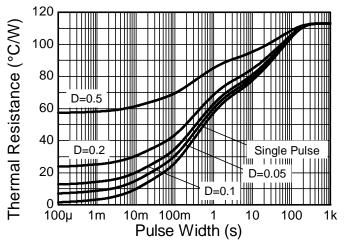
- 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is measured at t ≤ 5 seconds.
 7. Thermal resistance from junction to solder-point (at the end of the collector leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







Transient Thermal Impedance



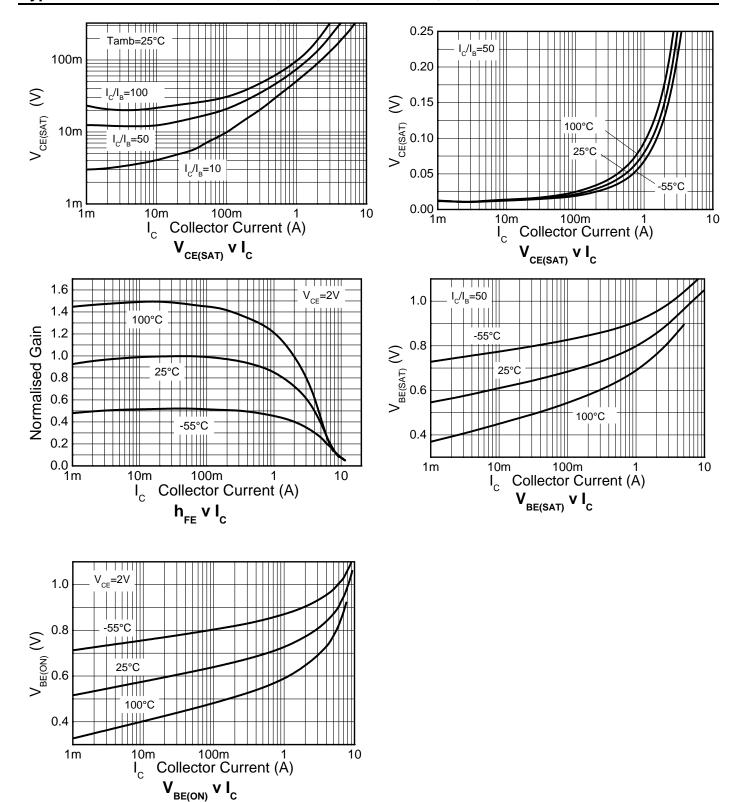
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-25	-55	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-20	-50	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.5		V	$I_E = -100 \mu A$
Collector-Base Cut-Off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -20V
Emitter Cut-Off Current	I _{EBO}	_		-100	nA	$V_{EB} = -6V$
Collector-Emitter Cut-Off Current	I _{CES}	_	_	-100	nA	V _{CES} = -20V
ON CHARACTERISTICS (Note 9)						
		300	500	_	_	$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain	h	300	450	900	_	$I_{C} = -1A, V_{CE} = -2V$
DC Current Gain	h _{FE}	150	250		_	$I_C = -3.5A$, $V_{CE} = -2V$
		10	_		_	$I_C = -10A$, $V_{CE} = -2V$
		_	-10	-15		$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-100	-130	mV	$I_C = -1A$, $I_B = -10mA$
		_	-165	-250		$I_C = -3.5A$, $I_B = -350mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	_	-1.1	V	$I_C = -3.5A$, $I_B = -350mA$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	_	-0.9	V	$I_C = -3.5A$, $V_{CE} = -2V$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	_	90		MHz	$V_{CE} = -10V$, $I_{C} = -50mA$, $f = 50MHz$
Output Capacitance	Cobo	_	62		pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(on)	_	95		ns	$V_{CC} = -10V, I_{C} = -2A$
Turn-Off Time	t _(off)		395		ns	$I_{B1} = I_{B2} = -40 \text{mA}$

Note: 9. Measured under pulsed conditions; pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$.



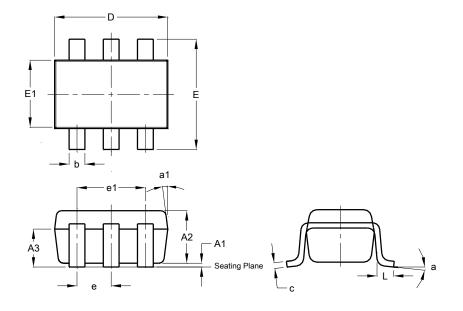
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline

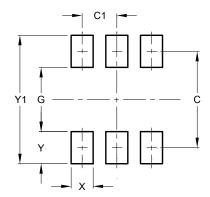
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26					
Dim	Min	Max	Тур		
A1	0.013	0.10	0.05		
A2	1.00	1.30	1.10		
А3	0.70	0.80	0.75		
b	0.35	0.50	0.38		
С	0.10	0.20	0.15		
D	2.90	3.10	3.00		
е	-	-	0.95		
e1	-	-	1.90		
Е	2.70	3.00	2.80		
E1	1.50	1.70	1.60		
L	0.35	0.55	0.40		
а	-	-	8°		
a1	-	-	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
Y1	3.20



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